

Scanning Beam Interference Lithography

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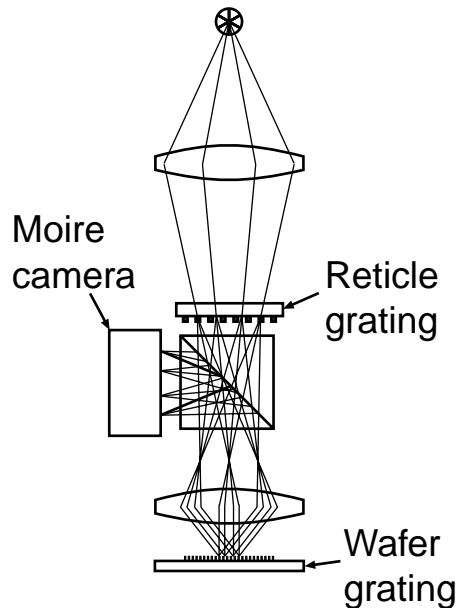
Research Objective

To develop interference lithography and fiducial grids as metrological tools.

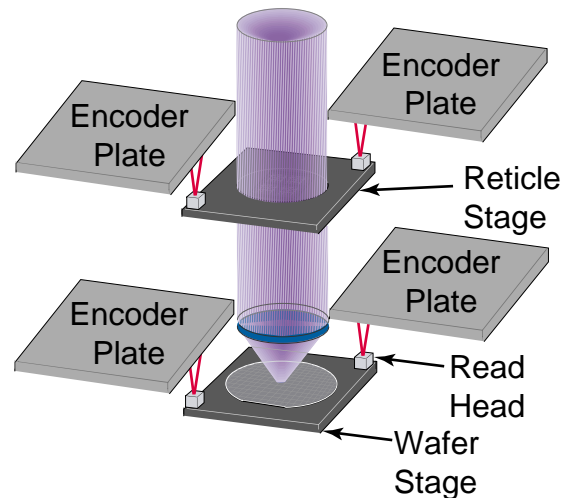
Short term goal: To pattern and measure gratings with repeatability of 5 nm over 300 mm diameter areas.

Application of Fiducial Grids to Metrology

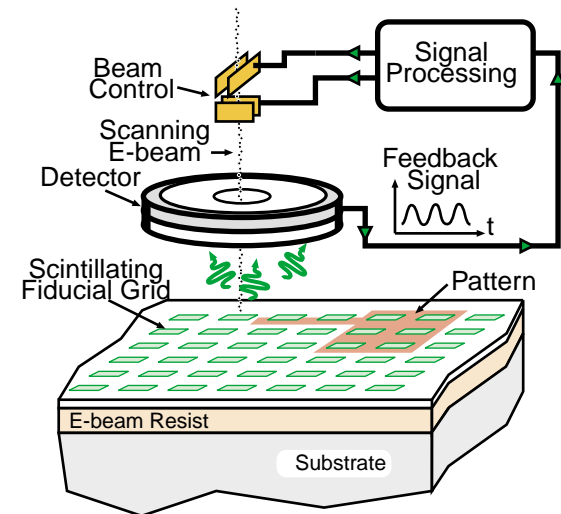
Lithography metrology.



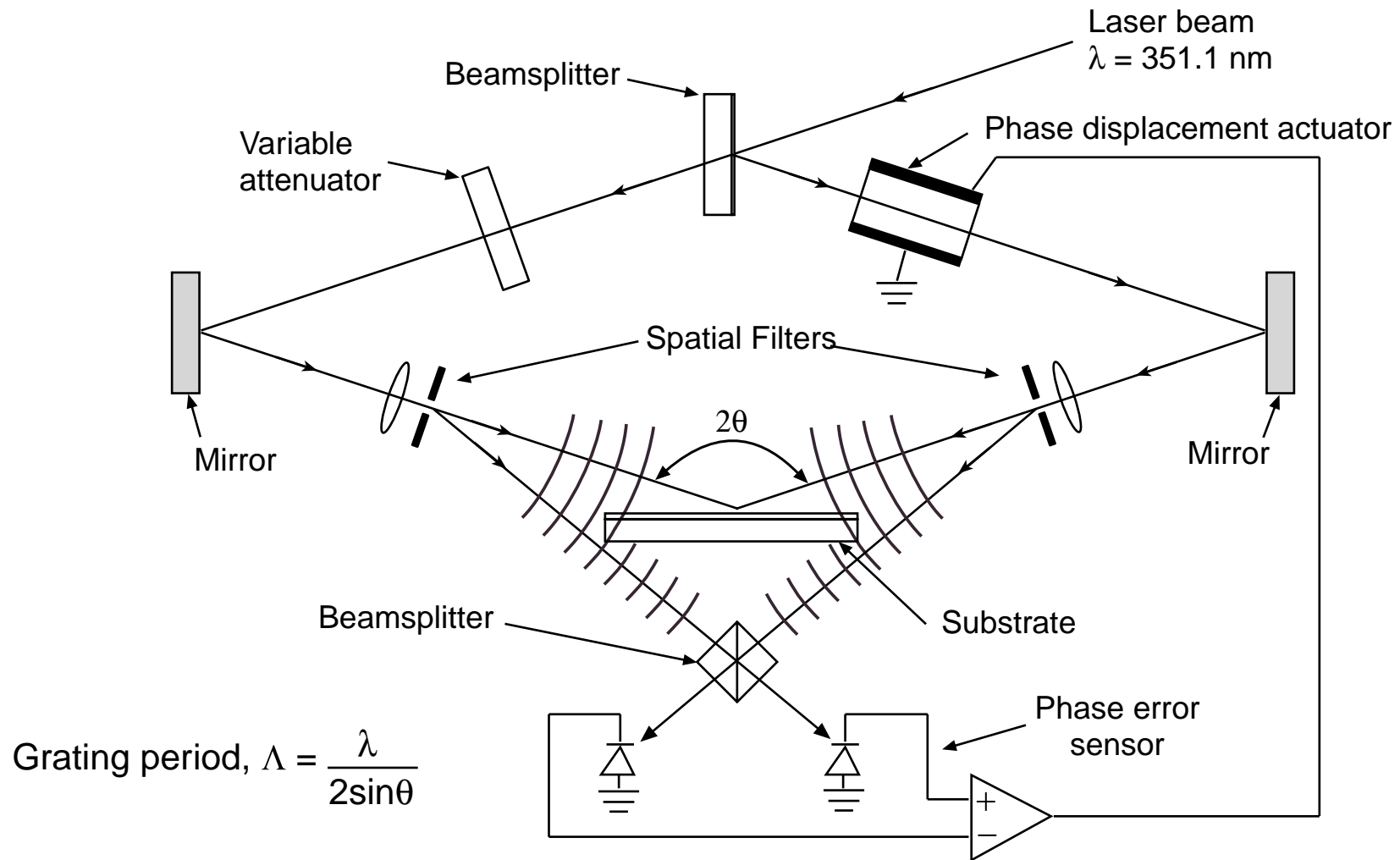
Stage encoders.



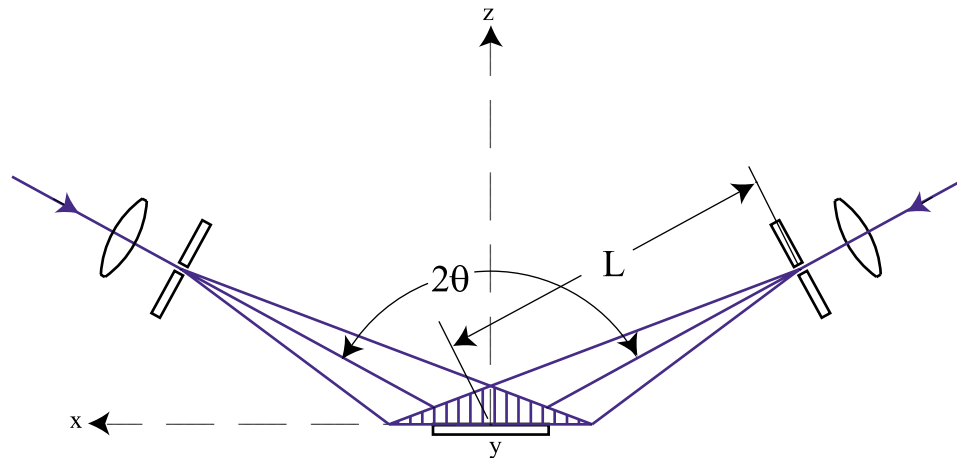
Reference for electron beam lithography



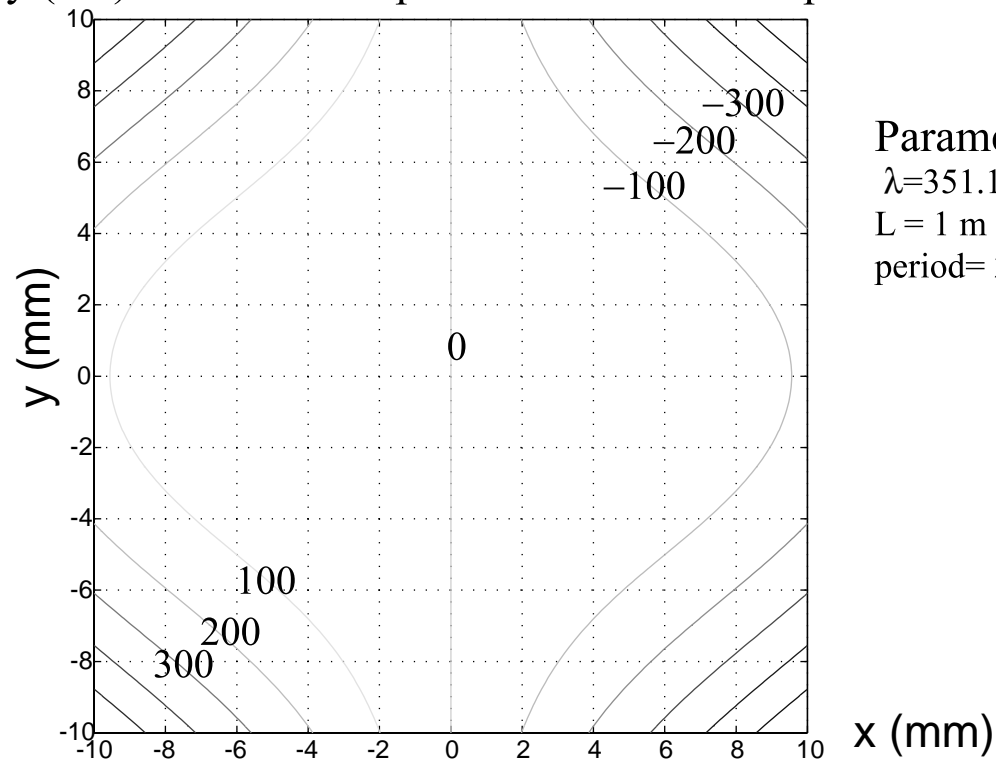
Traditional Interference Lithography



Phase Distortion of Interfered Spherical Waves



Discrepancy (nm) of interfered spherical waves with a perfect linear grating.



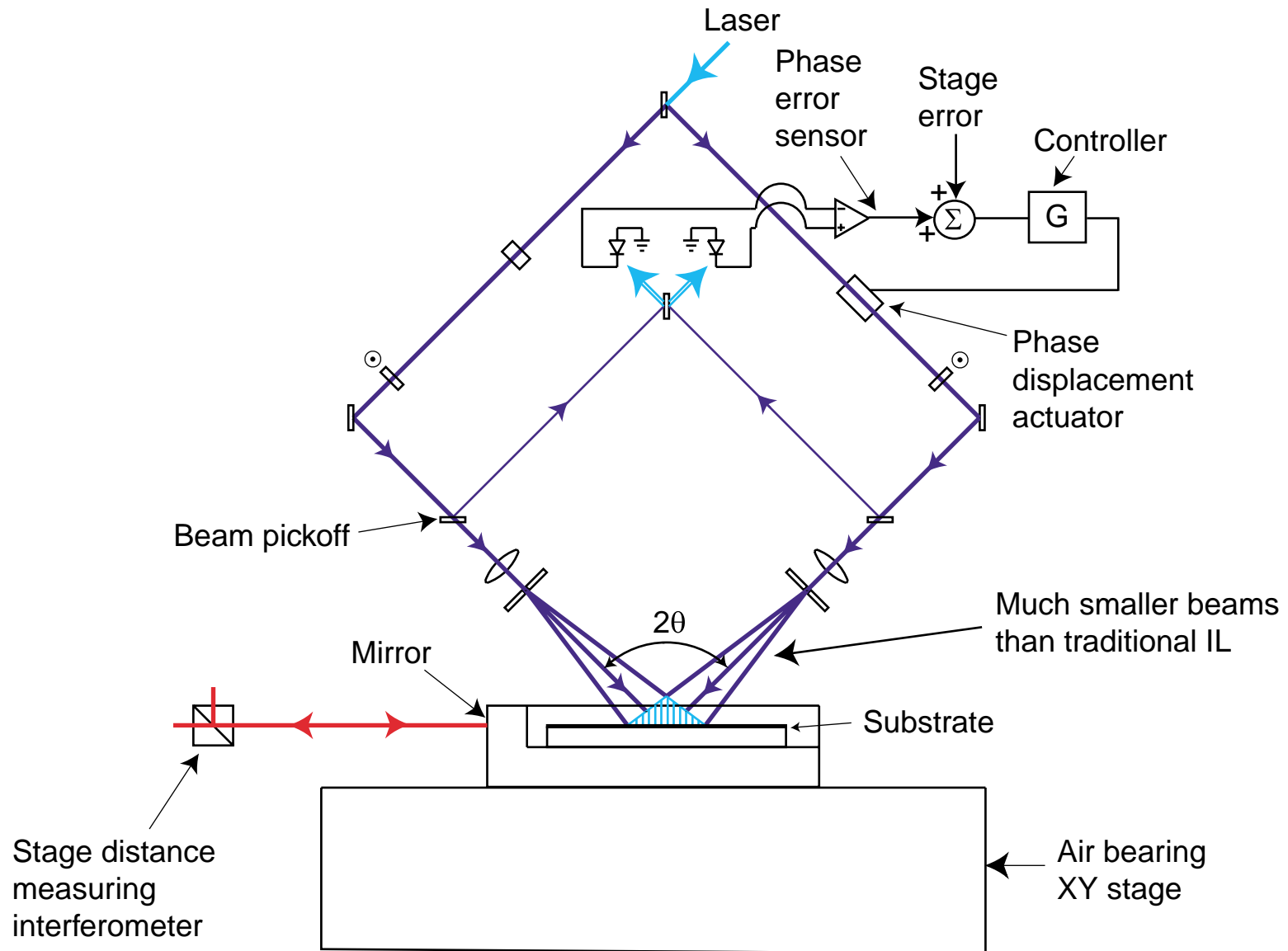
Parameters:

$$\lambda = 351.1 \text{ nm}$$

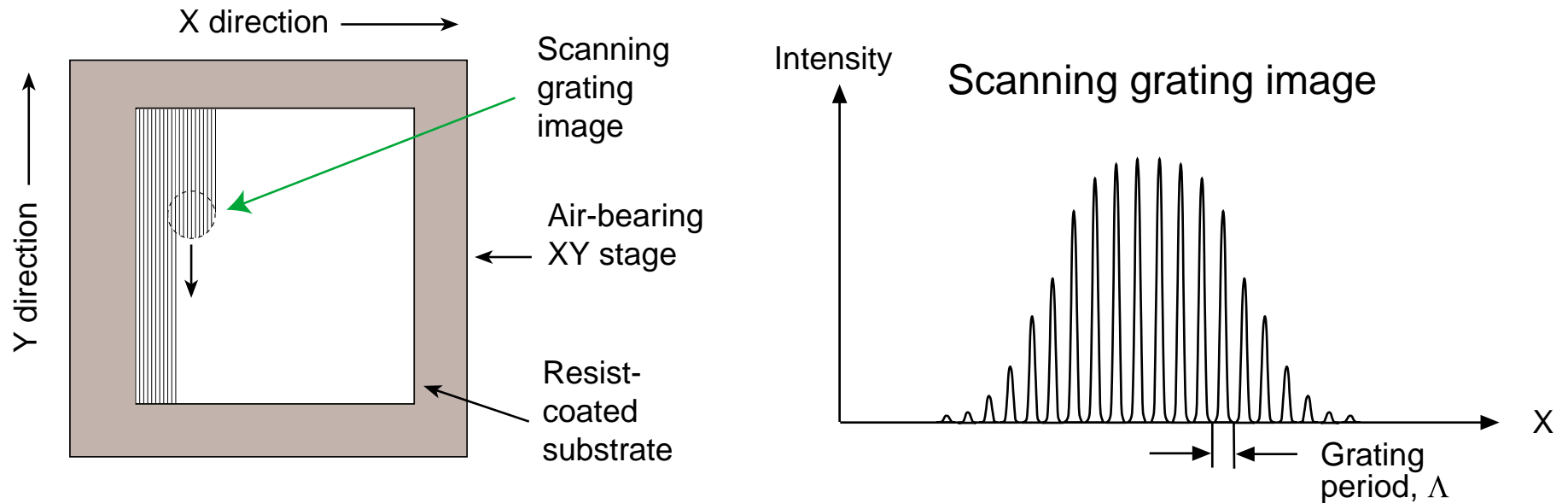
$$L = 1 \text{ m}$$

$$\text{period} = 200 \text{ nm}$$

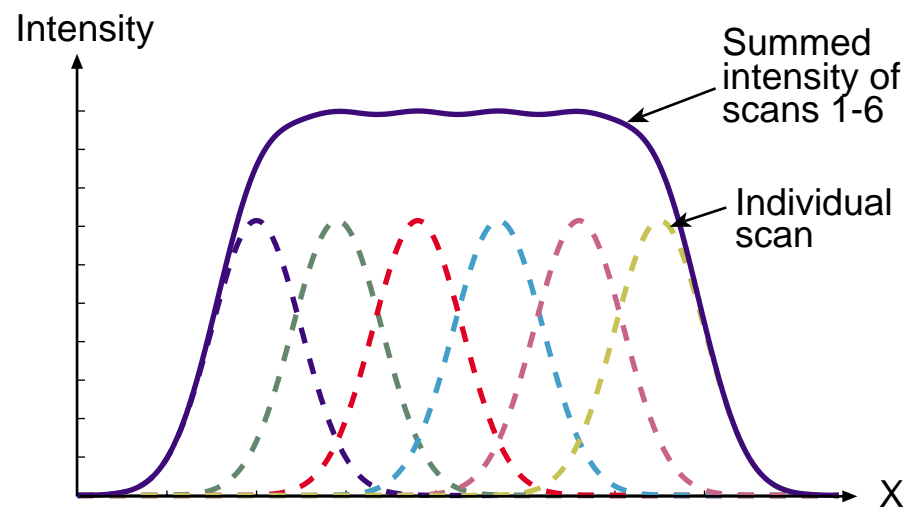
SBIL System Concept



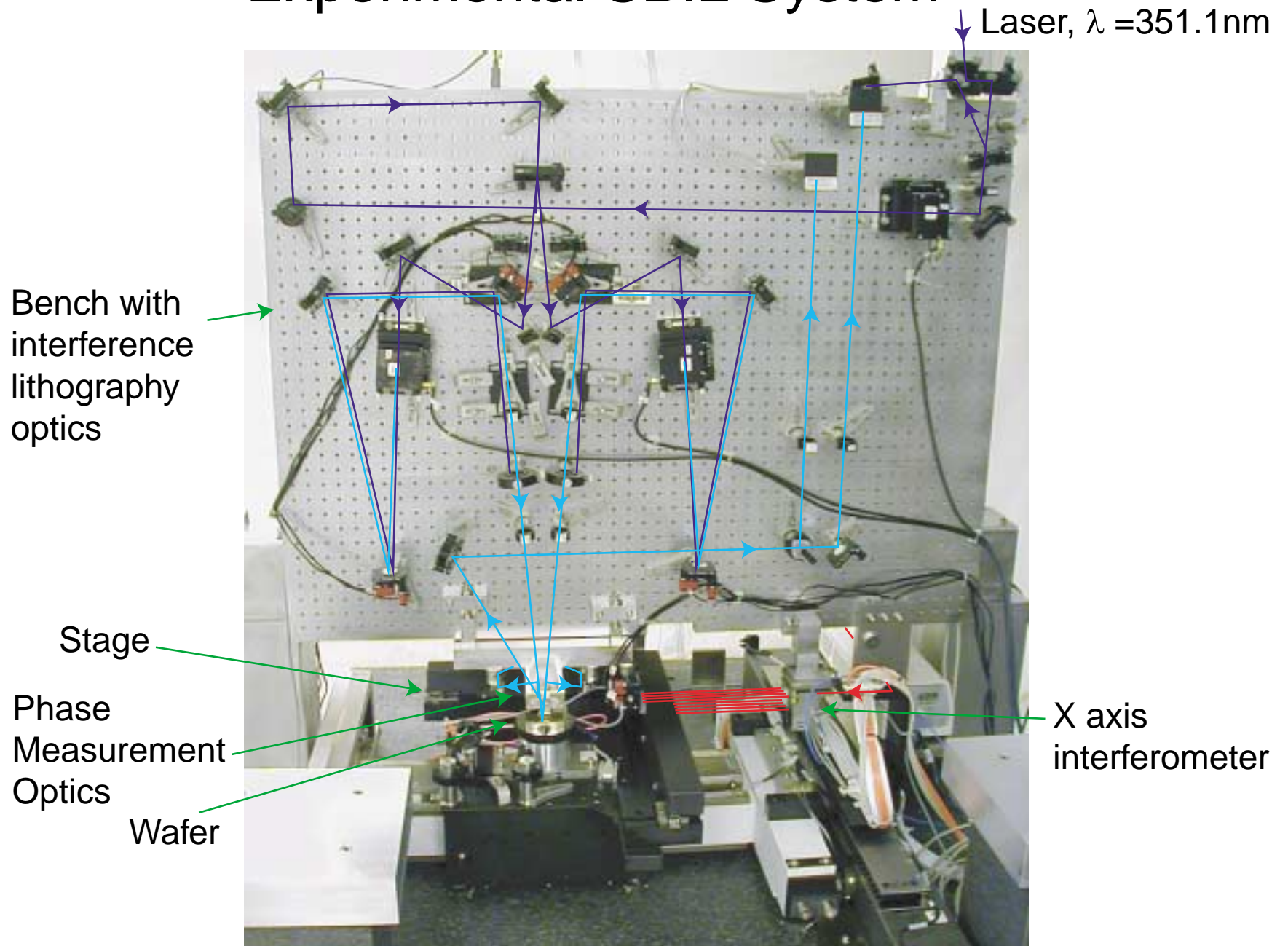
Grating Scanning Method



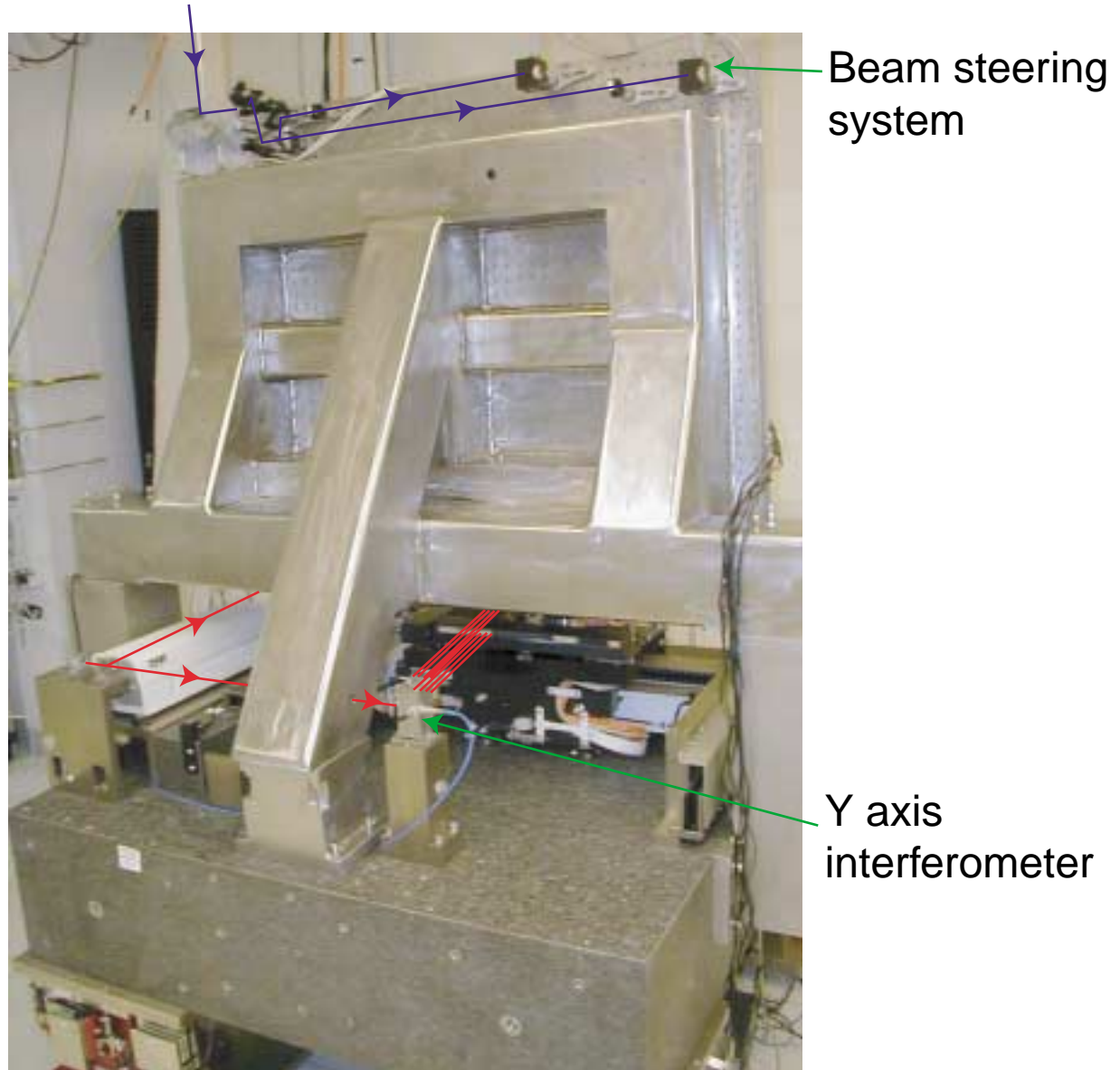
Overlapping scans closely approximate a uniform intensity distribution



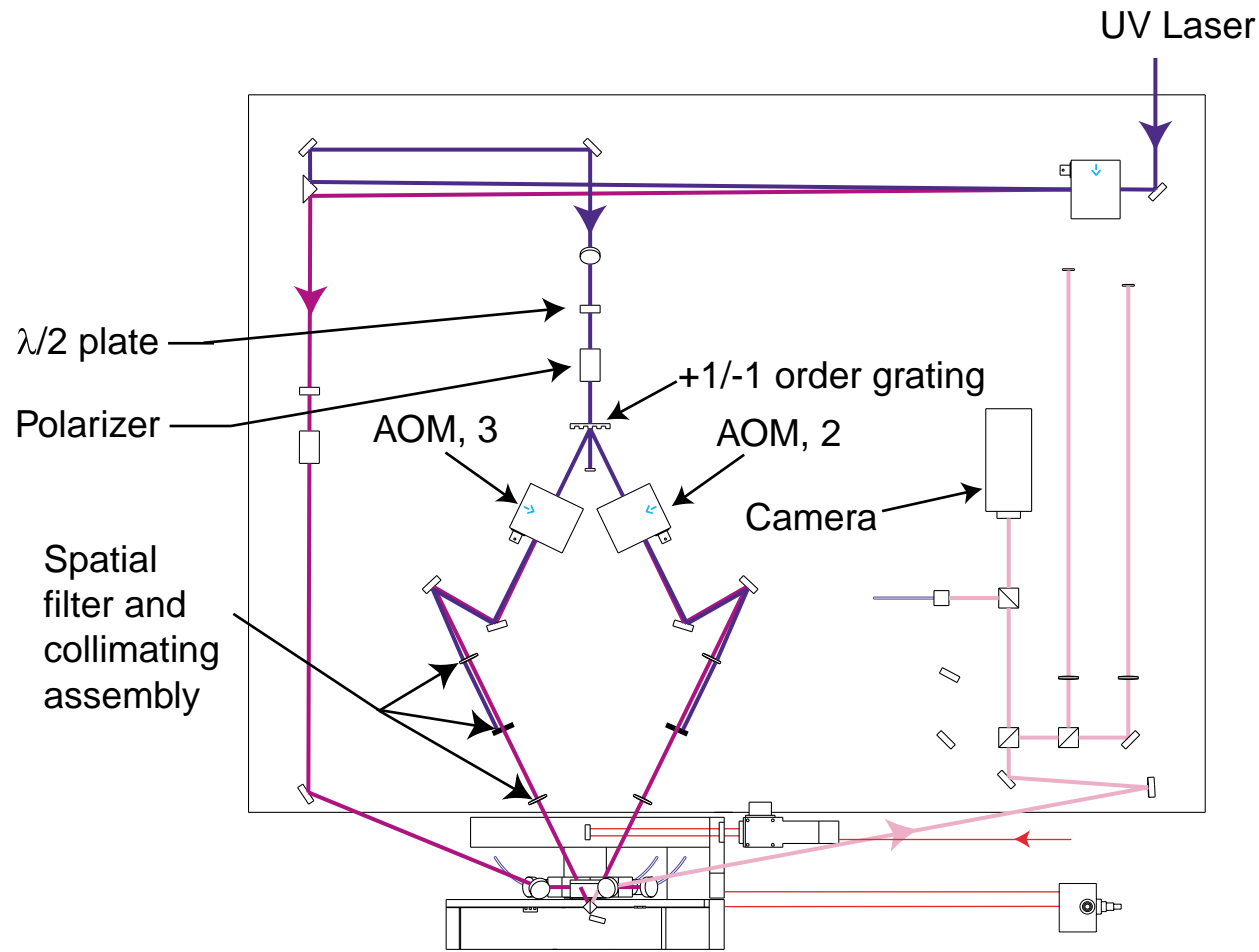
Experimental SBIL System



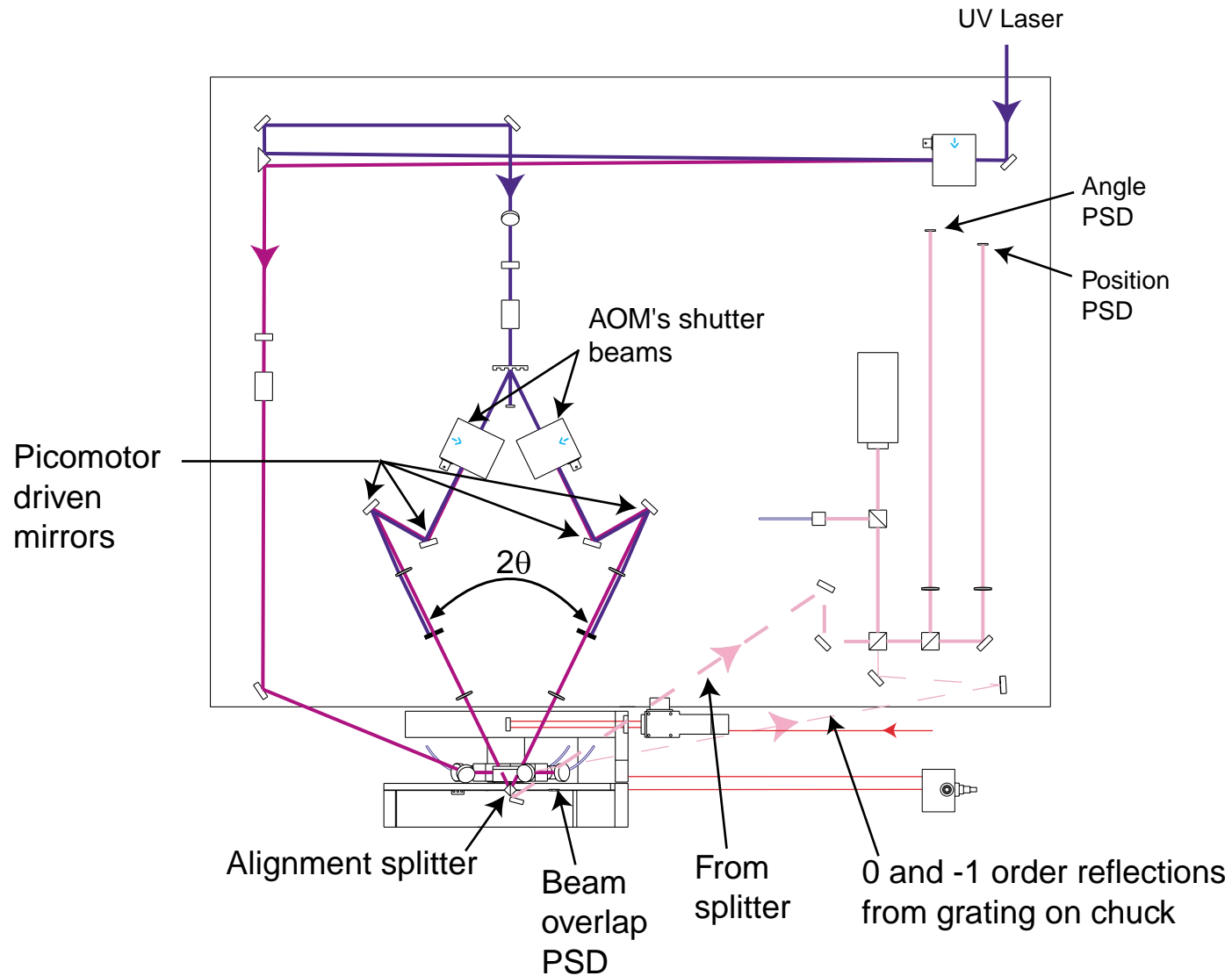
Experimental System, Rear View



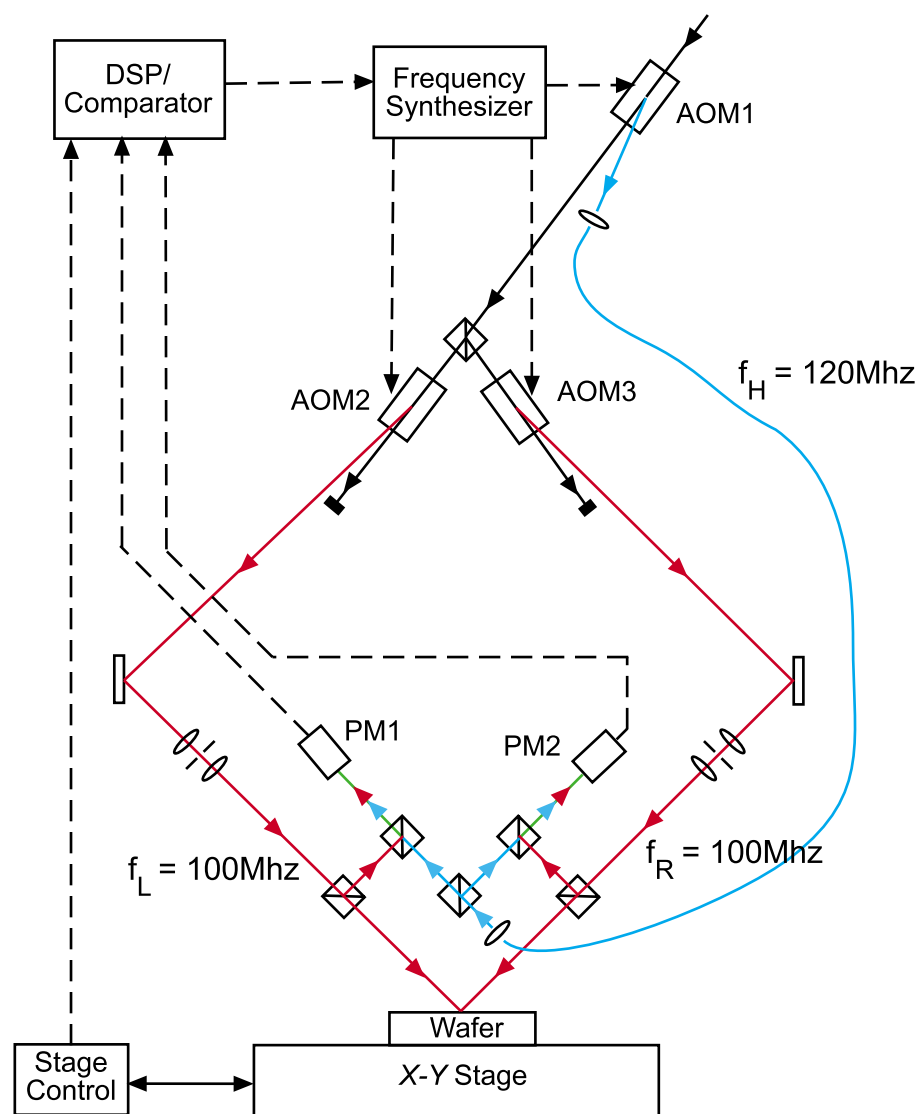
SBIL Beam Conditioning Optics



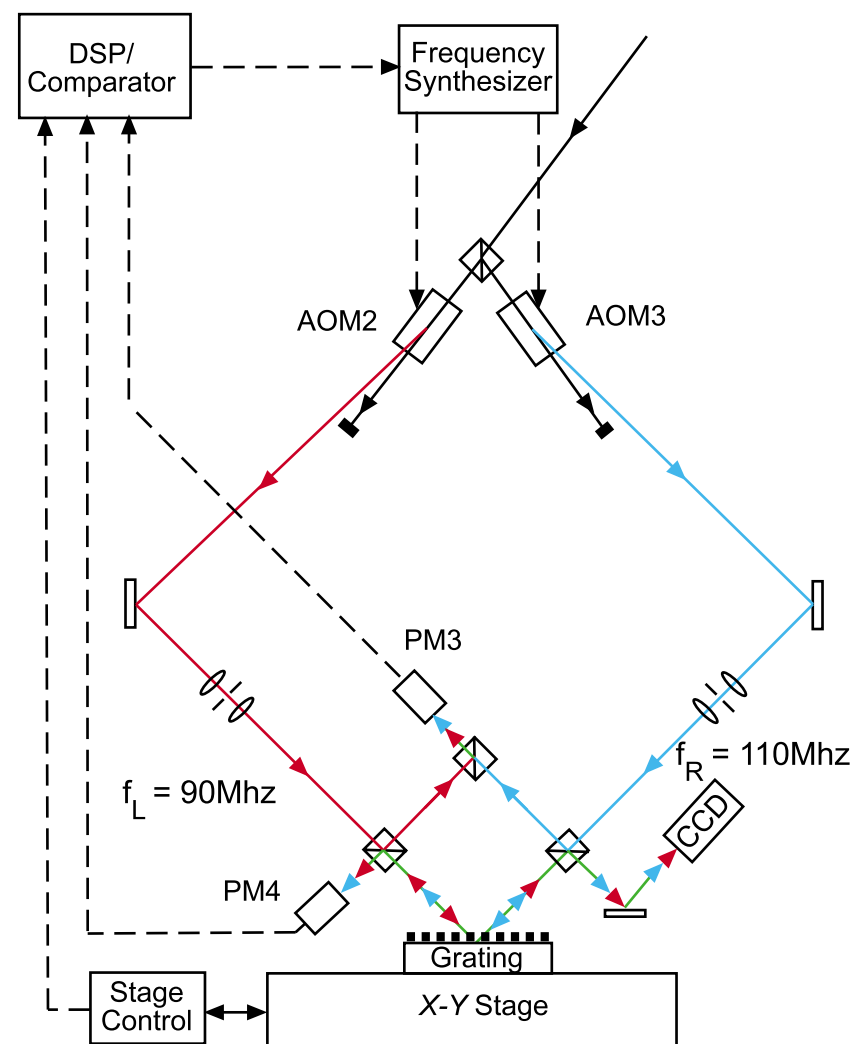
SBIL Alignment Optics



SBIL Reading and Writing Modes

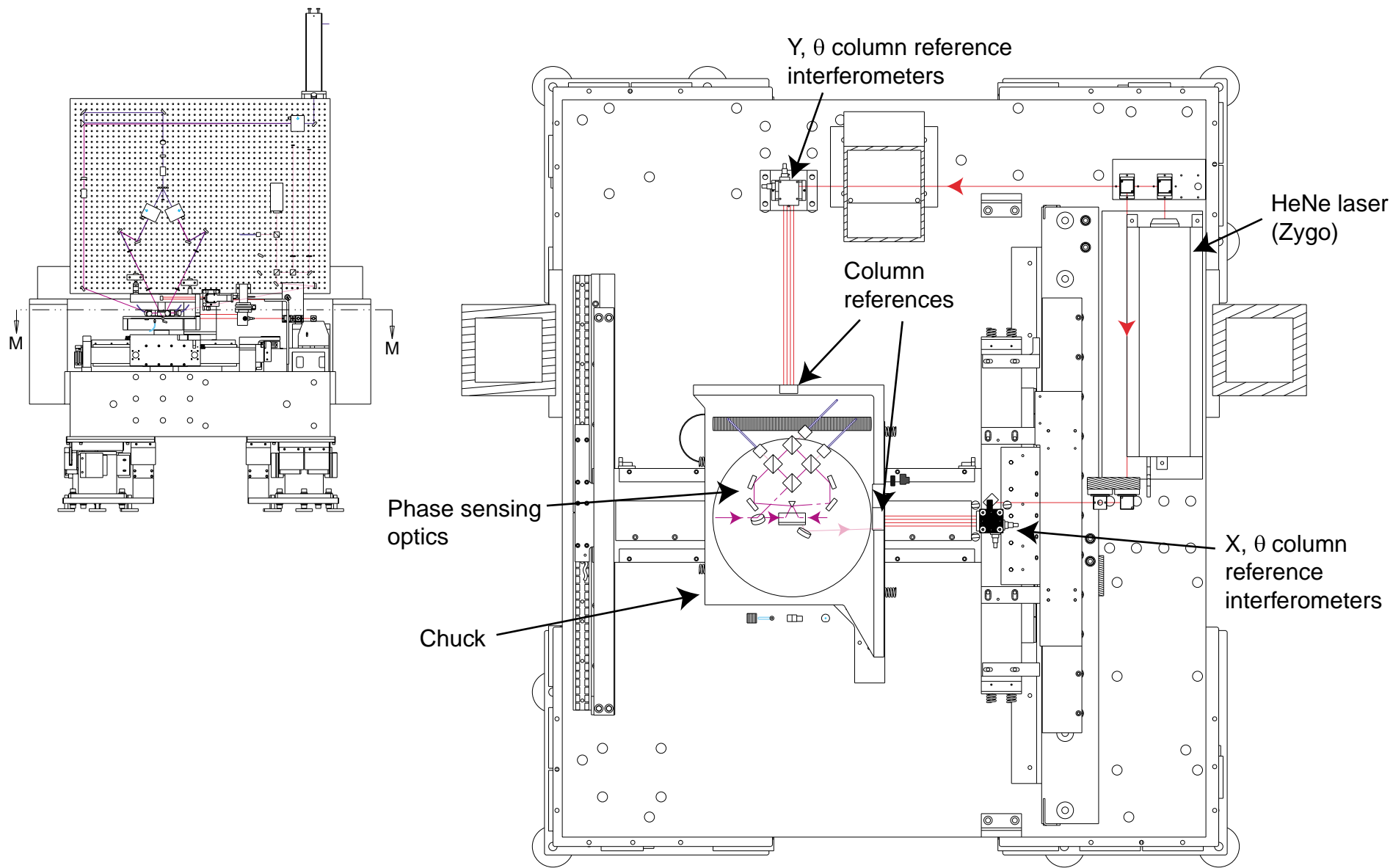


(a) Writing Mode



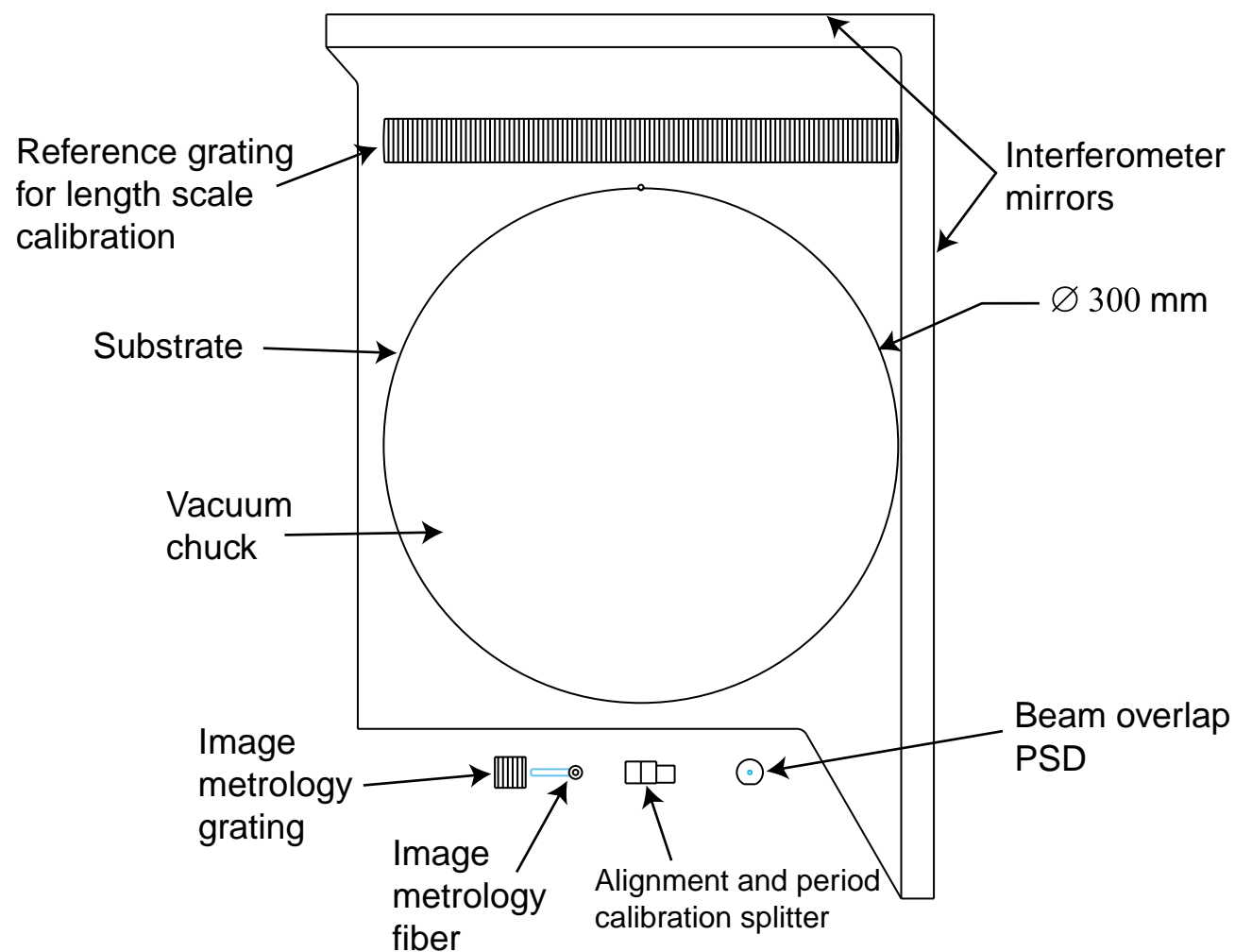
(b) Reading Mode

Stage and Lithography Metrology

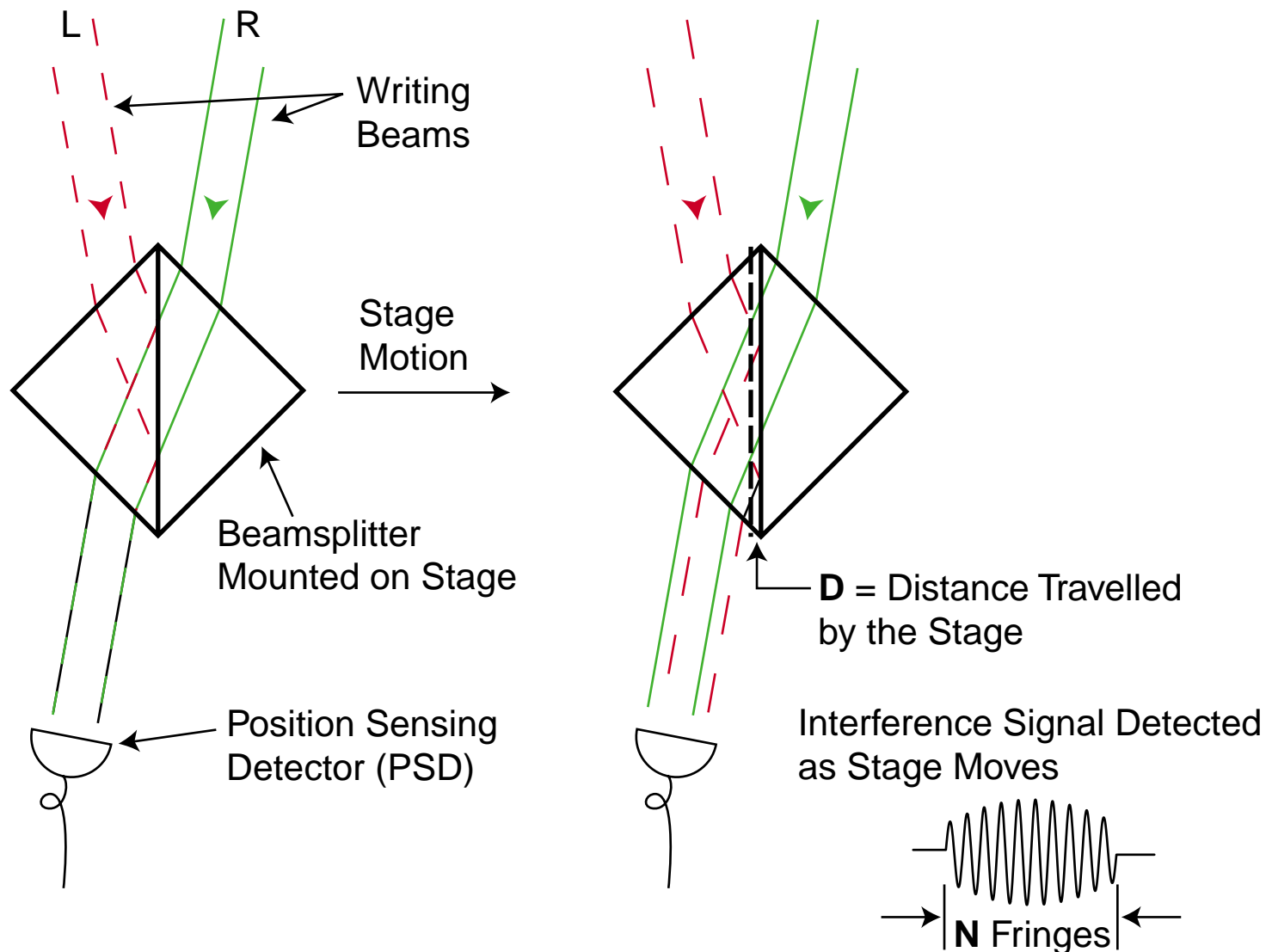


Section M-M

Chuck with Metrology References

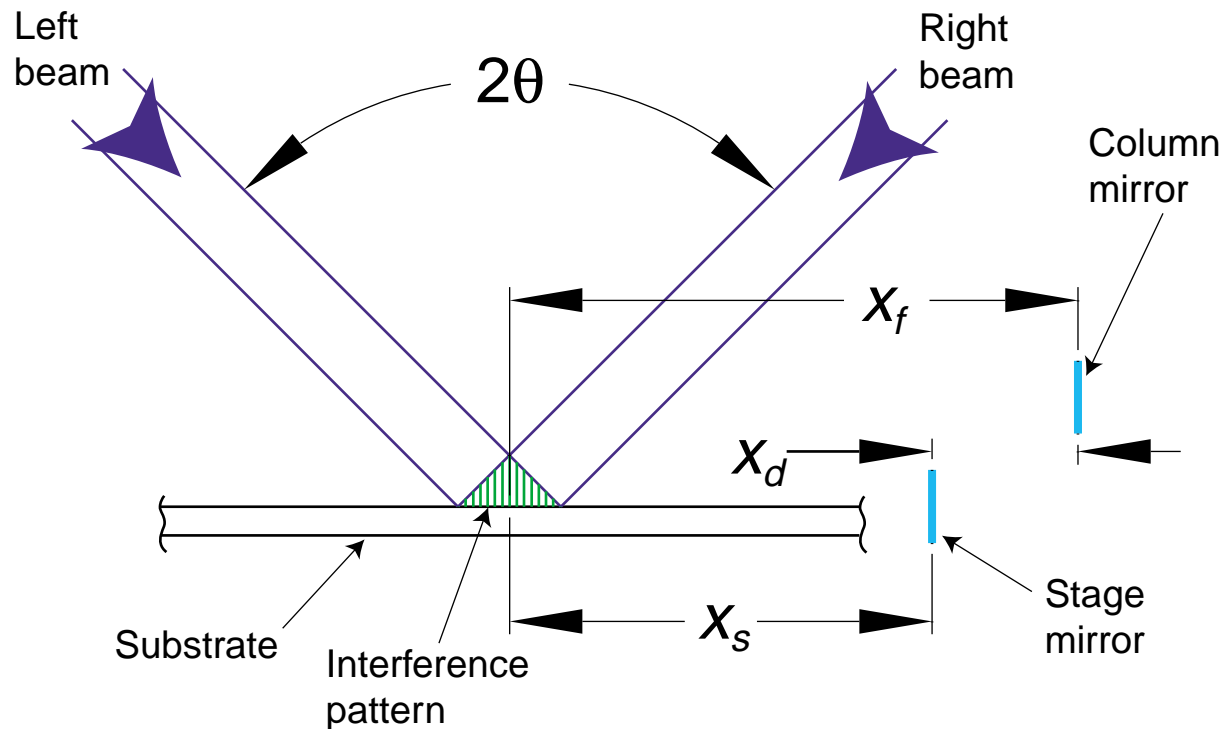


Period Measurement with a Beamsplitter



$$\text{Grating Period} = D/N$$

System Errors



Error Categories

Stage interferometer (X_d)

Fringe locking and metrology frame (X_f)

Substrate frame (X_s)

Period Control

Image Distortion

Conclusions

We are developing SBIL for producing gratings and grids with nanometer level distortions.

Key system requirements

- beam conditioning
- alignment
- placement accuracy